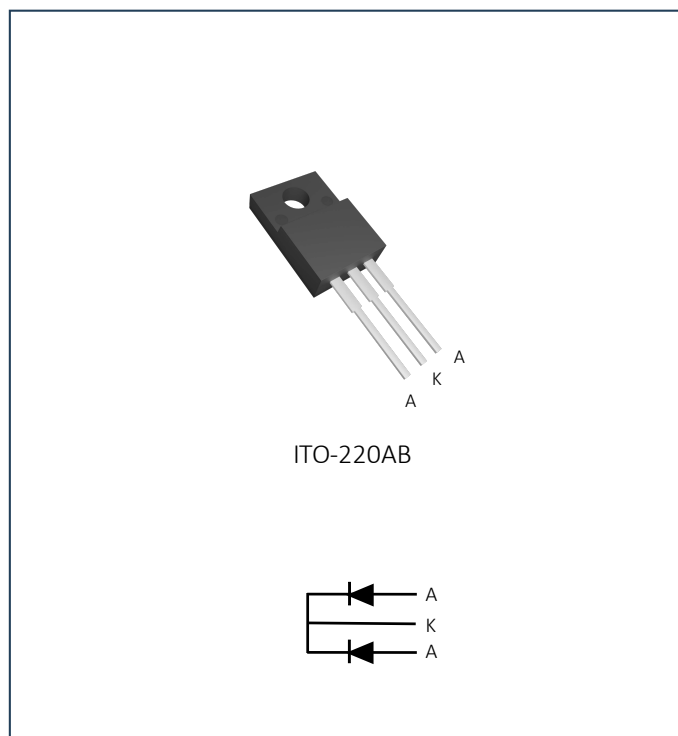


MUR20100FCT

快恢复二极管整流器

Fast Recovery Rectifier

封装外形 Package



主要参数 Device summary

Symbol	Value
$I_F(AV)$	20A
V_{RRM}	1000V
$V_F(typ)$	1.21V@10A 125°C
$I_R(typ)$	0.05mA@1000V 125°C
$T_{j(max)}$	150°C

机械数据 Mechanical Data

- 模塑料符合 UL 94 V-0 易燃等级, 符合 RoHS 标准
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- 端子: 镀锡引线, 可焊接 J-STD-002 和 JESD22-B102
Terminals: Tin plated leads, solderable per J-STD-002 and JESD22-B102
- 极性: 本体标记
Polarity: As marked on body

产品特点 Features

超快恢复时间 Ultra-fast recovery time

高结温 High Junction temperature

低漏电 Low leakage current

高可靠性 High reliability

环保产品 RoHS product

ITO-220AB 绝缘电压

ITO-220AB Package Insulated voltage:

≥3000V V_{bc} t=100mS

最大额定值 Maximum ratings

项目 Parameter	符合 Symbol	数值 Value	单位 Unit
反向电压 Peak repetitive reverse voltage	V _{RRM}	1000	V
平均正向电流 Average forward current	I _{F(AV)}	20	A
per device		10	
浪涌电流 Non-repetitive single pulse surge current t=8.3ms	I _{FSM}	150	A
结温 Junction temperature	T _j	-55~+150	°C
存储温度 Storage temperature	T _{STG}	-55~+150	°C

电特性 Electrical characteristics(T_C=25°C)

项目 Parameter	测试条件 Tests conditions		数值 Value			单位 Unit
			最小值(min)	典型值(typ)	最大值(max)	
反向电压 V _{RRM}	I _R =0.05mA		1000	-	-	V
反向漏电流 I _R	T _j =25°C	V _R =V _{RRM}	-	-	0.03	mA
	T _j =125°C		-	-	0.3	
正向电压 V _F	T _j =25°C	I _F =10A	-	-	1.85	V
	T _j =125°C	I _F =1A	-	0.72	-	
		I _F =5A	-	1.02	-	
		I _F =10A	-	1.21	-	
反向恢复时间 T _{rr}	T _j =25°C	Reverse recovery condition I _F =0.5A, I _R =1.0A, I _{rr} =0.25A	-	-	75	nS

热特性 Thermal characteristics(T_C=25°C)

项目 Parameter	符合 Symbol	数值 Value	单位 Unit
热阻 Thermal resistance from junction to case	R _{th(j-c)}	4.5	°C/W

典型特征曲线图 Typical Characteristic Curve

图 1: 正向电流与外壳温度

FIG 1: I_F - T_c

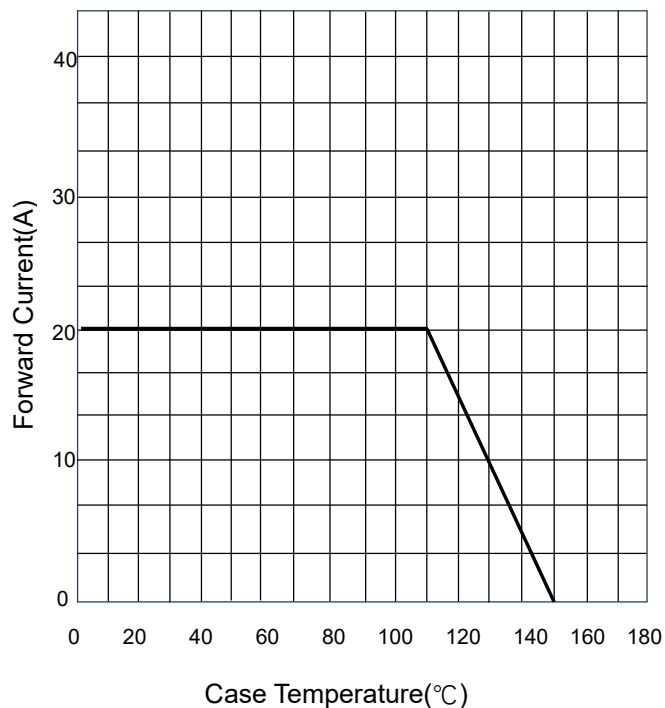


图 2: 正向浪涌循环次数

FIG 2: Surge Forward Current Capability

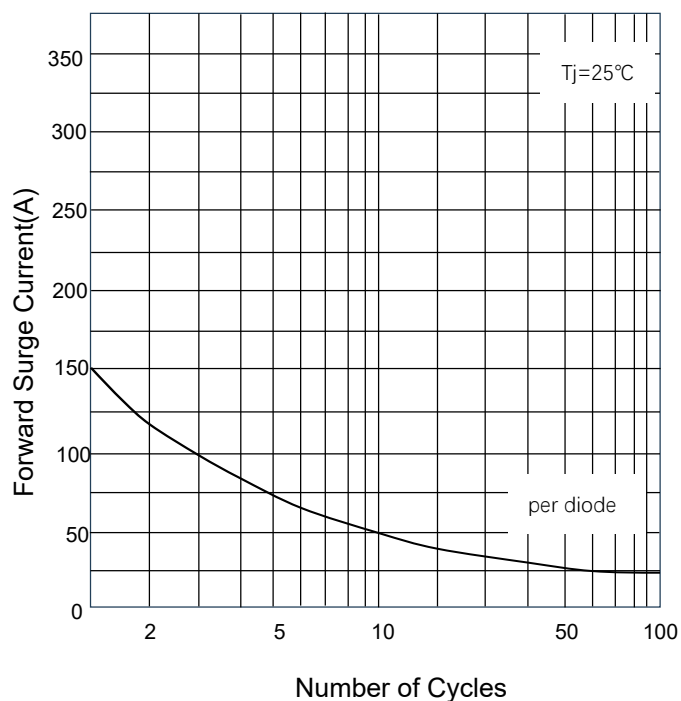


图 3: 反向电压与反向电流

FIG 3: V_R - I_R

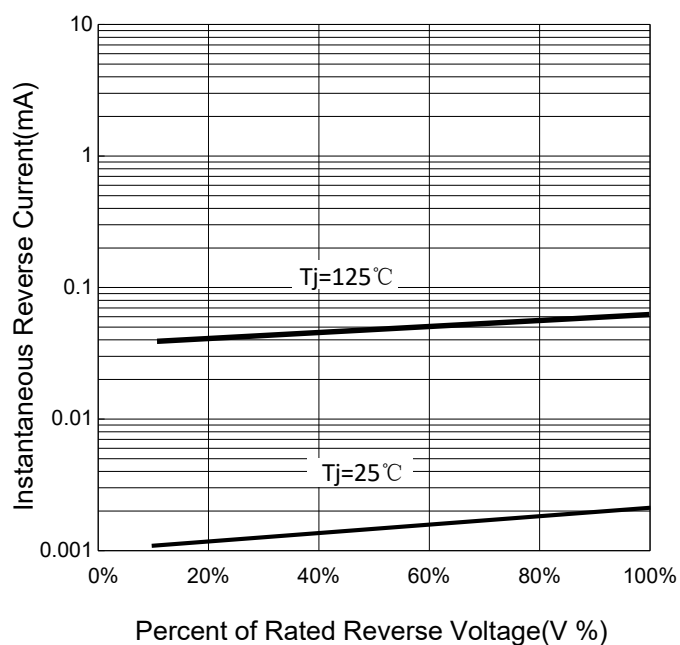
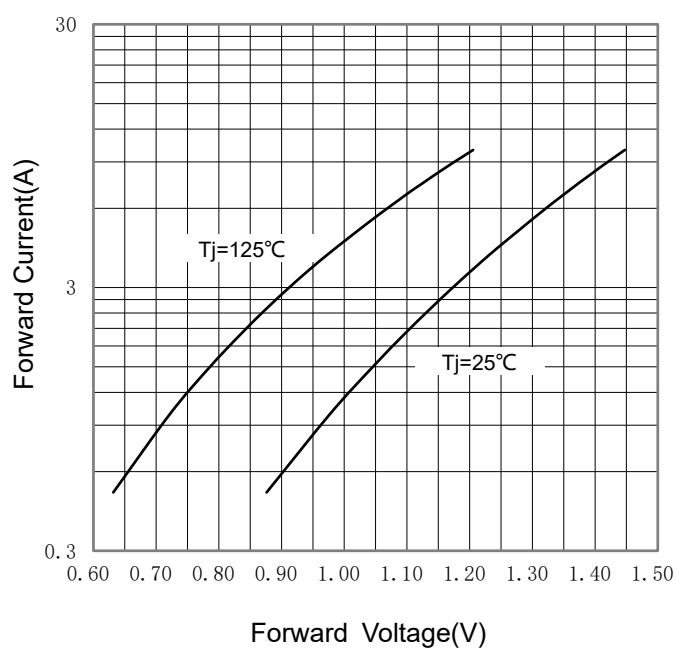
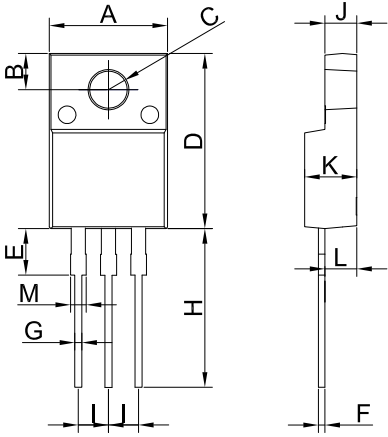


图 4: 正向电流与正向电压

FIG 4: I_F - V_F



外形尺寸图及焊盘布局参考 Outline Dimensions and Pad Layout Reference

ITO-220AB		Dim	Min	Typ	Max
		A	9.70	10.00	10.30
		B	3.00	3.20	3.40
		C	3.10	3.25	3.40
		D	15.10	15.40	15.70
		E	3.60	3.80	4.00
		F	0.45	0.55	0.65
		G	0.50	0.60	0.70
		H	12.80	13.20	13.60
		I	2.44	2.54	2.64
		J	2.50	2.70	2.90
		K	4.20	4.40	4.60
		L	2.60	2.70	2.80
		M	1.20	1.30	1.40
		尺寸单位: (mm) Dimensions in millimeters			

订购信息 Ordering Information

订单型号 Order code	印记 Marking	封装 Package	重量 Weight (g)	包装形式 Packing	基本包装 Base qty (pcs)	盒 Box (pcs)	箱 Carton (pcs)
CMUR20100FCT000P	MUR20100FCT	ITO-220AB	1.7	管装 Tube	50	1000	5000

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